



# Silicon PIN Photodiode

## **Description**

BPV20F is a high speed and high sensitive PIN photodiode in a plastic package with a cylindrical side view lens. The epoxy package itself is an IR filter, spectrally matched to GaAs or GaAs/GaAlAs IR emitters ( $\lambda_{\rm p}$  = 950 nm).

Lens radius and chip position are perfectly matched to the chip size, giving high sensitivity without compromising the viewing angle.

In comparison with flat packages the cylindrical lens package achieves a sensitivity improvement of 20 %.



#### **Features**

- Large radiant sensitive area (A = 7.5 mm<sup>2</sup>
- Wide viewing angle  $\varphi = \pm 65^{\circ}$
- · Improved sensitivity
- · Fast response times
- TO-92 plastic package with IR filter
- Filter designed for 950 nm transmission
- · Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **Applications**

Infrared remote control and free air transmission systems in combination with IR emitter diodes (TSU...- or TSI...-Series).

#### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse Voltage		V <sub>R</sub>	60	V
Power Dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	215	mW
Junction Temperature		Tj	100	°C
Operating Temperature Range		T <sub>amb</sub>	- 55 to + 100	°C
Storage Temperature Range		T <sub>stg</sub>	- 55 to + 100	°C
Soldering Temperature	t ≤ 5 s	T <sub>sd</sub>	260	°C
Thermal Resistance Junction/ Ambient		R <sub>thJA</sub>	350	K/W

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# **BPV20F**

# **Vishay Semiconductors**



#### **Electrical Characteristics**

 $T_{amb}$  = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward Voltage	$I_F = 50 \text{ mA}$	$V_{F}$		1	1.3	V
Breakdown Voltage	$I_R = 100 \mu A, E = 0$	V <sub>(BR)</sub>	60			V
Reverse Dark Current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>		2	30	nA
Diode capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0$	C <sub>D</sub>		70		pF
Serial Resistance	V <sub>R</sub> = 12 V, f = 1 MHz	R <sub>S</sub>		400		Ω

## **Optical Characteristics**

 $T_{amb}$  = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Open Circuit Voltage	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	V <sub>o</sub>		360		mV
Temp. Coefficient of V <sub>o</sub>	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK <sub>Vo</sub>		- 2.6		mV/K
Short Circuit Current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	I <sub>k</sub>		55		μА
Reverse Light Current	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm},$ $V_{R} = 5 \text{ V}$	I <sub>ra</sub>	40	60		μА
Temp. Coefficient of I <sub>ra</sub>	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm},$ $V_{R} = 10 \text{ V}$	TK <sub>Ira</sub>		0.1		%/K
Absolute Spectral Sensitivity	$V_R = 5 \text{ V}, \lambda = 870 \text{ nm}$	s(λ)		0.35		A/W
	$V_R = 5 \text{ V}, \ \lambda = 950 \text{ nm}$	s(λ)		0.6		A/W
Angle of Half Sensitivity		φ		±65		deg
Wavelength of Peak Sensitivity		$\lambda_{p}$		950		nm
Range of Spectral Bandwidth		$\lambda_{0.5}$		870 to 1050		nm
Quantum Efficiency	$\lambda = 950 \text{ nm}$	η		90		%
Noise Equivalent Power	$V_R = 10 \text{ V}, \lambda = 950 \text{ nm}$	NEP		4 x 10 <sup>-14</sup>		W/√ Hz
Detectivity	$V_R = 10 \text{ V}, \ \lambda = 950 \text{ nm}$	D <sup>*</sup>		6 x 10 <sup>12</sup>		cm√Hz/W
Rise Time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t <sub>r</sub>		100		ns
Fall Time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t <sub>f</sub>		100		ns
Cut-Off Frequency	$V_R = 12 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 870 \text{ nm}$	f <sub>c</sub>		4		MHz
	$V_R = 12 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 950 \text{ nm}$	f <sub>c</sub>		1		MHz

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### **Typical Characteristics**

T<sub>amb</sub> = 25 °C unless otherwise specified

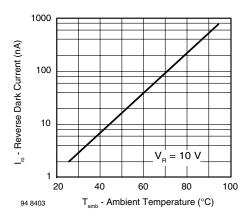


Figure 1. Reverse Dark Current vs. Ambient Temperature

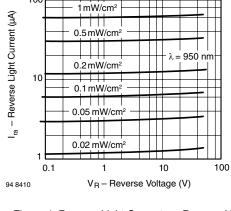


Figure 4. Reverse Light Current vs. Reverse Voltage

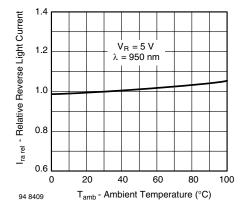


Figure 2. Relative Reverse Light Current vs. Ambient Temperature

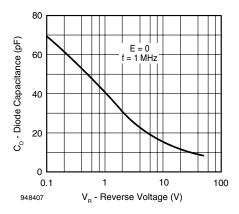


Figure 5. Diode Capacitance vs. Reverse Voltage

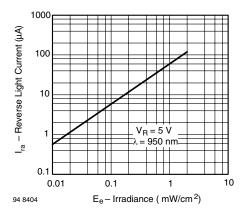


Figure 3. Reverse Light Current vs. Irradiance

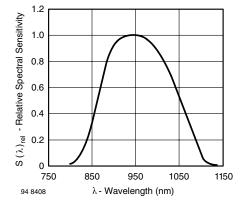


Figure 6. Relative Spectral Sensitivity vs. Wavelength

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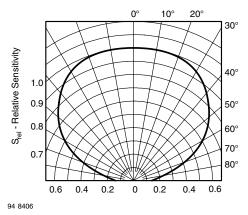
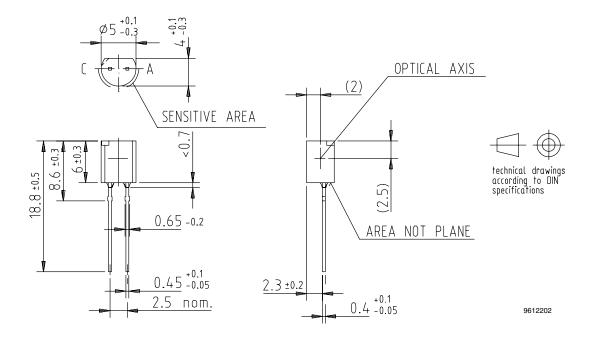


Figure 7. Relative Radiant Sensitivity vs. Angular Displacement

# Package Dimensions in mm





## **Vishay Semiconductors**

#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

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